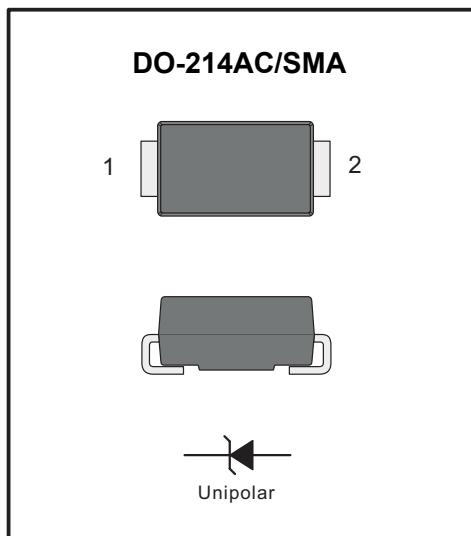


SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Features

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Metal silicon junction,majority carrier conduction
- ◆ Low power loss,high efficiency
- ◆ Built-in strain relief,ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed:
250 °C/10 seconds at terminals

Mechanical Data

- ◆ Case : JEDEC DO-214AC/SMA molded plastic body
- ◆ Terminals : Solderable per MIL-STD-750,Method 2026
- ◆ Polarity : Color band denotes cathode end Mounting
- ◆ Position : Any
- ◆ Weight : 0.002 ounce, 0.07 grams

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60Hz,resistive or inductive load,for capacitive load current derate by 20%.

Parameter	SYMBOLS	SS12	SS13	SS14	SS15	SS16	SS18	SS110	SS1150	SS1200	UNITS
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	40	50	60	80	100	150	200	V
Maximum RMS voltage	V _{RMS}	14	21	28	35	42	56	70	105	140	V
Maximum DC blocking voltage	V _{DC}	20	30	40	50	60	80	100	150	200	V
Maximum average forward rectified current at TL(see fig.1)	I _(AV)						1.0				A
Peak forward surge current 8.3ms single half sine-wave superimposed onrated load (JEDEC Method)	I _{FSM}						30				A
Maximum instantaneous forward voltage at 1.0A	V _F	0.45	0.55		0.70			0.85		0.9	V
Maximum DC reverse current TA=25°C at rated DC blocking voltage TA=125°C	I _R			0.5				0.2			mA
				10.0			5.0		2.0		
Typical junction capacitance (NOTE 1)	C _J	110				90					pF
Typical thermal resistance (NOTE 2)	R _{θJA}				88.0						°C/W
Operating junction temperature range	T _J		-50 to +125				-50 to +150				°C
Storage temperature range	T _{STG}				-50 to +150						°C

Note:1.Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2.P.C.B. mounted with 0.2x0.2"(5.0x5.0mm) copper pad areas

Fig.1 Forward Current Derating Curve

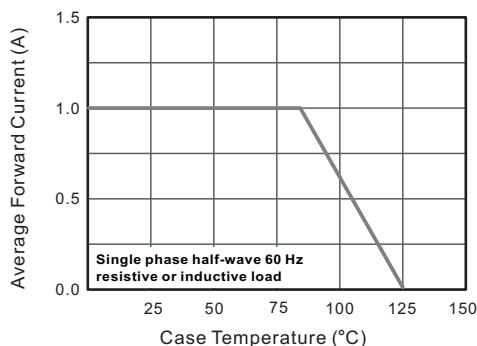


Fig.2 Typical Reverse Characteristics

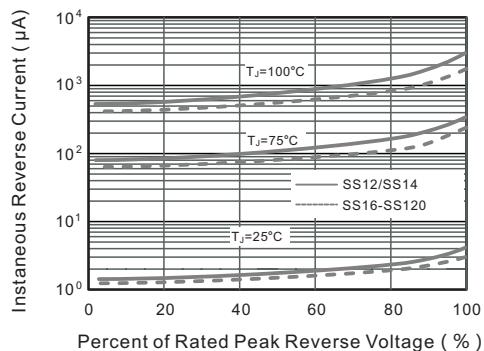


Fig.3 Typical Forward Characteristic

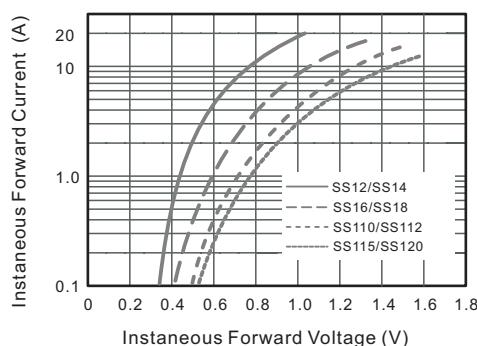


Fig.4 Typical Junction Capacitance

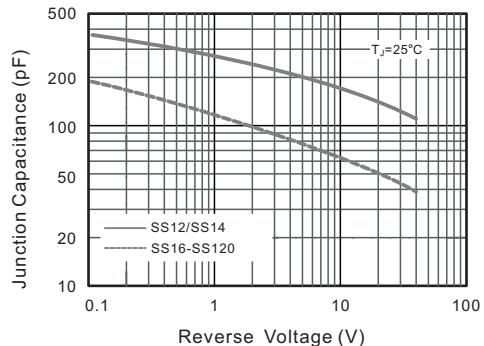


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

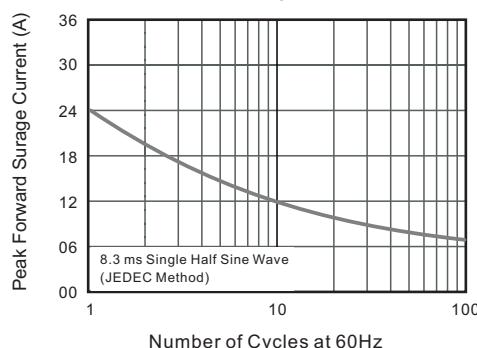
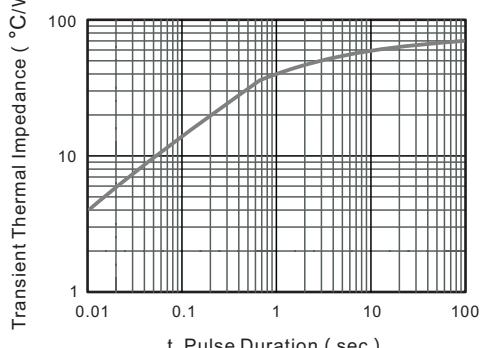


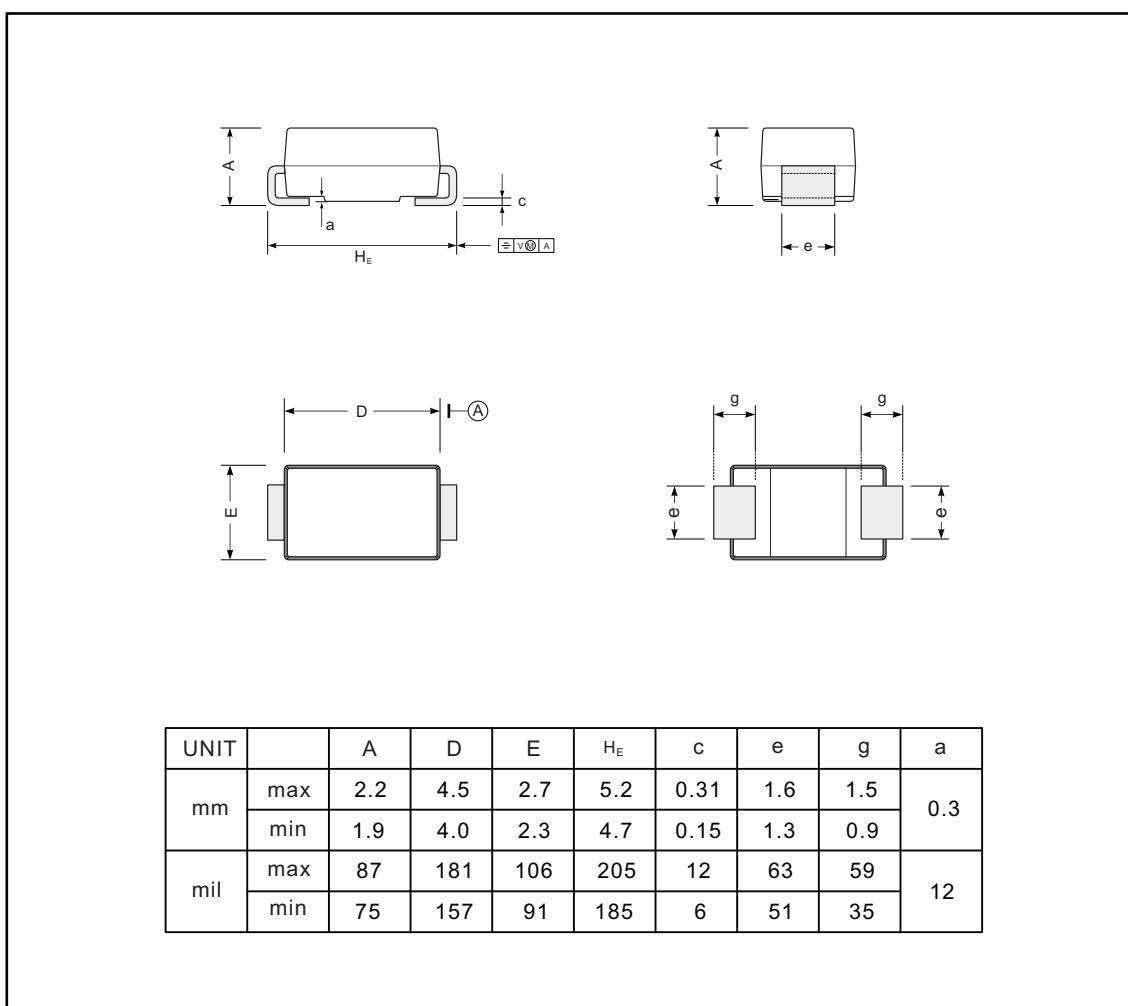
Fig.6- Typical Transient Thermal Impedance



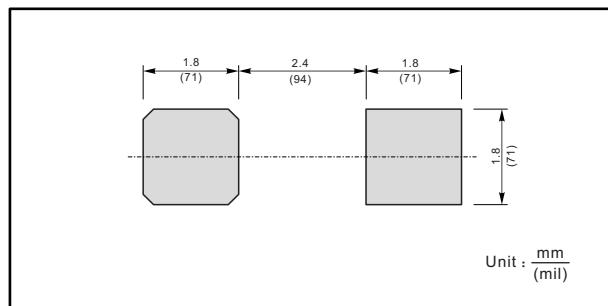
PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SMA



The recommended mounting pad size



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